

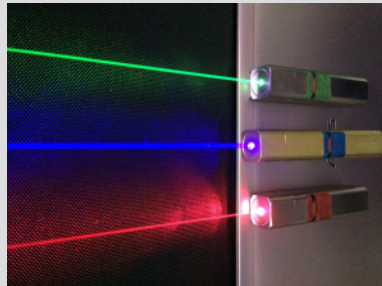
Group III Nitride

Semiconductors
for massive energy saving
future communication
our health

InN GaN AlN

- Direct bandgap with energy covering a wide range from the deep ultraviolet to infrared region of the electromagnetic spectrum
- Suitable for both optoelectronic and electronic devices

Blue & Green Laser Diodes



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- Data storage
- Displays
- Projector

Light Emitting Diodes (LEDs)

- Solid state lighting
- Horticulture
- Water purification
- Communication



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Power Electronics



By Sam Churchill
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- Power supplies
- Consumer electronics
- Clean energy
- Automobile

RF Electronics

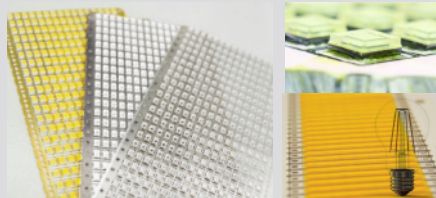
- Mobile communications infrastructure
- Military systems



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Applications

Characteristics



GaN-on-Si LEDs © 2015 Plessey Semiconductors

Compact
Efficient
Long-lasting
Controllable



GaN transistors © 2013 GaN Systems Inc.

High-current
High-voltage
High switching speed
High efficiency